

Rev.E Mar.-2016

WR0<50P ММ Ё QSQ æ Ñ ç s ll 1 Silicon NPN transistor in a TO-92LM Plastic Package.

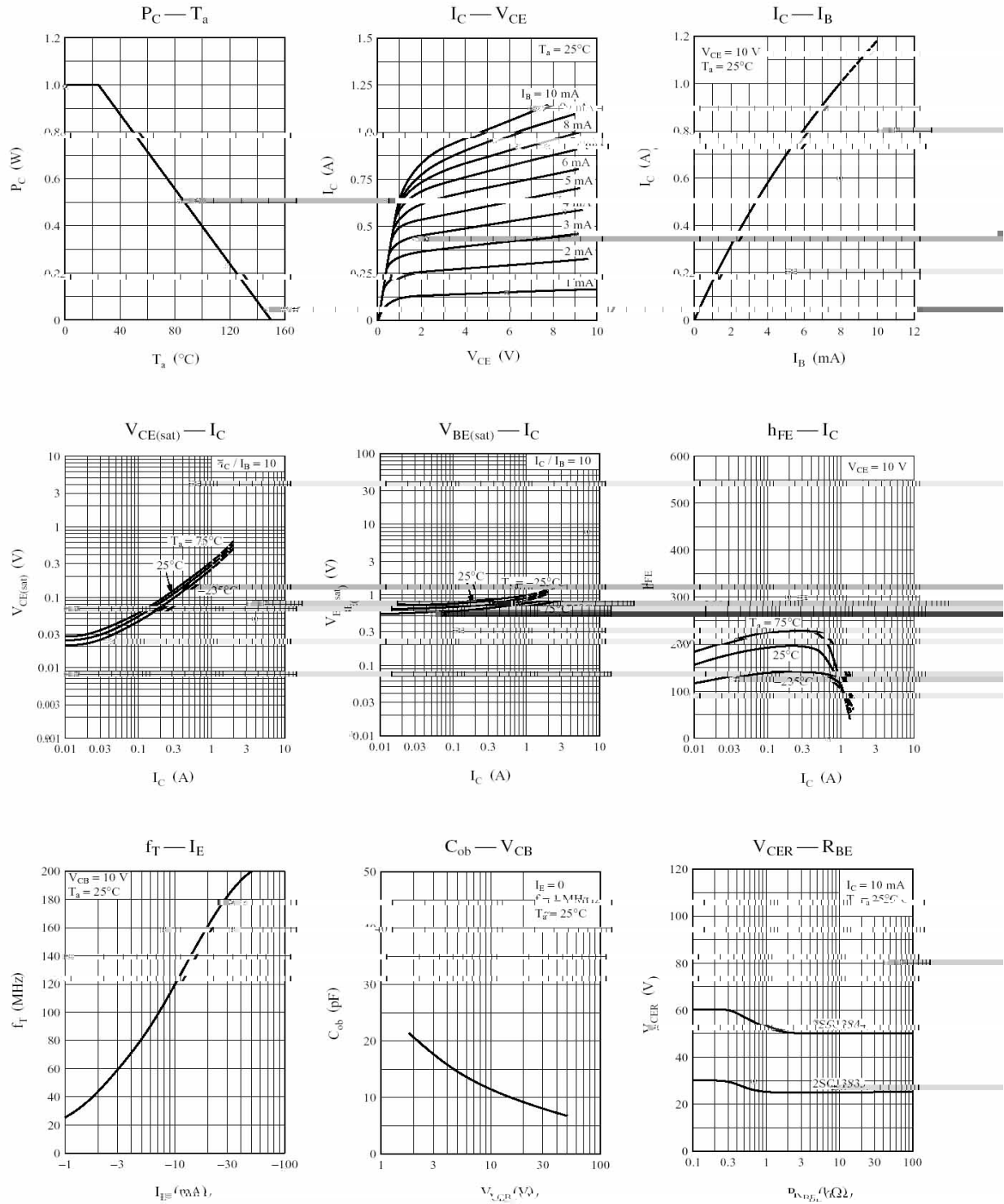
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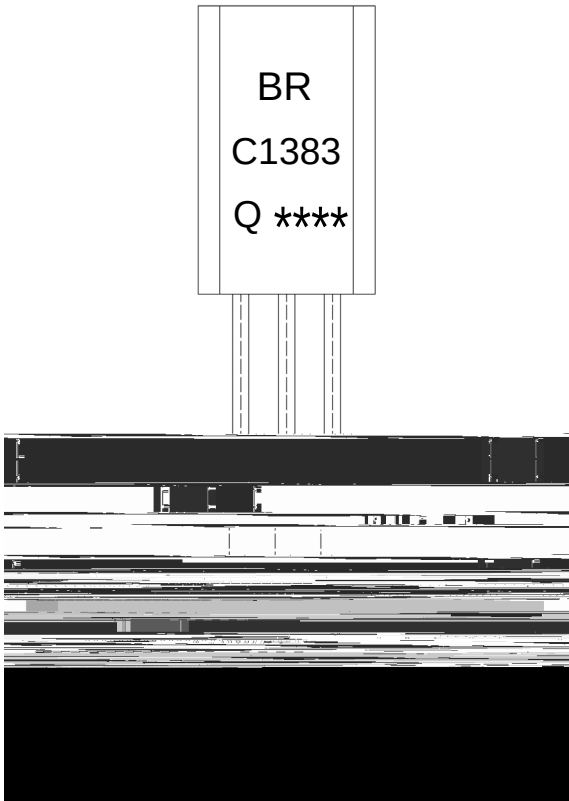
Low $V_{CE(sat)}$, complementary pair with 2SA683.

Low V

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	30	V
Collector to Emitter Voltage	V_{CEO}	25	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	1.0	A
Collector Current – Continuous(Pulse)	I_{CP}	1.5	A
Collector Power Dissipation	P_C	1.0	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter Symbol Unit S W





公司代码	公司代码
EU:	公司代码
F46;6	公司代码
T:	公司代码
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Note:	
BR:	Company Code.
C1383:	Product Type.
Q:	h _{FE} Classifications Symbol
****:	Lot No. Code,code change with Lot No.



- Note:

- 1.Preheating:25~150 ℃ , Time:60~90sec.
- 2.Peak Temp.:255 ° 5 ℃ , Duration:5 ° 0.5sec.
3. Cooling Speed: 2~10 ℃ /sec.

□ $\dot{y} \chi 270^{\circ} 5 \uparrow$

 $\tau_H \approx 10^{10} \text{ sec.}$

Temp.:270 ° 5 t

Time:10 ° 1 sec

"Ω τ γ ε / BULK

^ V γ E / AMMO

Package Type	Units					Dimension (unit mm3)	
	Units/tape /	Tape/Inner Box /	Rows/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Inner Box	Outer Box
TO-92LM	2,500	1	100	10	25,000	328×230×42	480×346×235 547×407×268